ナノサイズ単一磁性体の磁化挙動

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磁気メモリーの高密度化に伴い、その最小構成単位はナノサイズ領域に入りつつある。こうした状況では、個々のナノ磁性体の性質やスピンダイナミクスを定量的に把握することが、将来のデバイス設計・開発に不可欠である。これまで我々は異常ホール効果を利用した超高感度磁化検出法を開発し、単一ナノ粒子の磁気計測を可能にした。(Fig.1) この

Fig.1 (a) 異常 Hall 効果測定に用いた L1₀ FePt (001)単結晶ドット(* 50 nm×' 10 nm)と十字型電極の SEM 像, (b) (a)の単一 FePt ドットの温度 10K, 300K における磁化曲線

方法により $L1_0$ FePt や Co/Pt 人工格子をはじめとする機能磁性材料のナノサイズ領域における磁化挙動を系統的に明らかにしてきた。そうした準静的測定に加え、実際のデバイスの高速動作を意識して高速パルス磁場に対する単一粒子(直径 120 nm) の応答を調べた。一例として保磁力の磁場印加時間依存性について調べた結果を Fig.2 に示す。ナノ秒から秒に及ぶ広い時間領域にわたり磁化反転は古典的な Neel-Arrhenius 則で説明でき、反転過程が熱揺らぎに支配されていることがわかる。

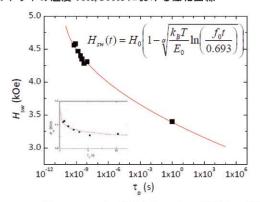


Fig.2 単一Co/Pt人工格子ドットの保磁力の印加磁場時間依存性.(赤線は Neel-Arrhenius 則)

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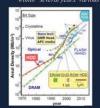
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Outline

For future advancement in magnetic and spin electronic devices, it is essential to understand the magnetic behavior and spin dynamics of a single nanomagnet. However, no effective method has been available for detection of such extremely small magnetic moment. To overcome this difficulty, we have newly developed a highly sensitive magnetic detection technique utilizing the anomalous Hall effect (AHE). This technique has systematically revealed the magnetic behaviors of various magnetic materials in the nanoscale regime. In this article, we demonstrate how single nanomagnets of L10 FePt and Co/Pt multilayers behave depending on their size, especially focusing on the magnetization reversal process and the bistability condition necessary for digital memory use. In addition, we have also developed the nanoindentation technique using a scanning probe microscope for fabrication of nanostructures.

Background

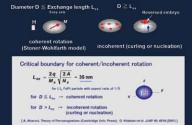
Magnetic Recording (HDD) can realize highest data density and its value will reach 1 Tbits/in2
within several years. Various spin tropice, devices are also expected for future technologies



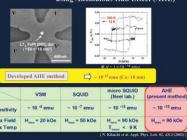


How does such a tiny magnet behave in response to H, T, etc?

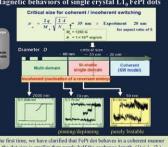
Theoretical prediction of micromagnetics



Newly developed sensitive magnetic detection method using Anomalous Hall Effect (AHE)



Magnetic behaviors of single crystal L1₀ FePt dots



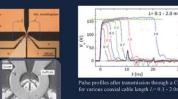
Magnetization dynamics in single nanomagnet

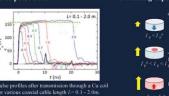




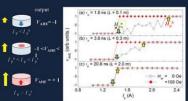
This max H is insufficient to switch Co/Pt dot!!

Generation of ns pulse field

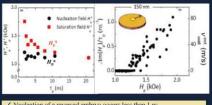




Switching experiment of [Co/Pt] dot by nanosecond pulse field

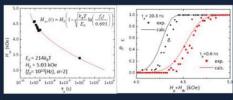


Nucleation & Wall dynamics in single [Co/Pt] dot



Domain wall velocity is proportional to field amplitude velocity $V = \mu (H_p - H_n)$ $\mu : mobility (= 130 \text{ m s}^{-1} \text{ Oe}^{-1})$ We can determin spin damping parameter α from μ

Thermal fluctuation of magnetiization in ns regime



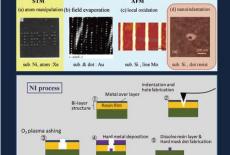
The classic Neel-Arrhenius model on thermal fluctuation reproduces the switching probability very well, indicating that

Necl-Arrhenius model is good approximation even in ns regime

Summary

- utilizing the Anomalous Hall Effect (AHE) with sensitivity of 10-15 emu.
- By means of the AHE method, we have successfully measured the on L1. FePt and Co/Pt.
- We have developed a fast pulse field generator being able to generate a pulse field with rise time less than 0.4 ns and amplitude of 4.0 kOe
- The ns switching experiment has revealed that magnetization switching ds via very rapid nucleation of a reversed embryo followed by its
- The classic Neel-Arrhenius model on thermal fluctuation rec switching probability very well, indicating that Neel-Arrhenius model is good

Development of SPM nanofabrication technique



Dot fabrication process

